# NSN 5961-00-417-0240

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-417-0240

**Inclosure Material:** 

Metal

**Overall Length:** 

0.375 inches

## **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Unthreaded hole

Features Provided:

## Hermetically sealed case

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 100.0 breakdown voltage, collector-to-emitter, base open and 7.0

breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current

# Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector preset

## **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

## Shelf Life:

N/a

## Unit Of Measure:

---

## Demilitarization:

No

Fiig:

A110a0